ON Semiconductor

Is Now



To learn more about onsemi™, please visit our website at www.onsemi.com

onsemi and ONSEMI. and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/ or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use onsemi products for any such unintended or unauthorized application,



ON Semiconductor®

FSA3051 —High Performance SPDT Analog Switch with Over-Voltage Tolerance

Features

Low On Capacitance: 7.7 pF Typical
Low On Resistance: 6 Ω Typical

■ Low Pow er Consumption: 1 µA Maximum

- 15 μ A Maximum I_{CCT} over an Expanded Voltage Range (V_{IN} =1.8 V, V_{CC} =5.5 V)

■ Wide -3 db Bandw idth: 1.0 GHz

Packaged in Ultra Small 6-Lead TMLP

Broad V_{CC} Operating Range: 1.6 V to 5.5 V

 Over-Voltage Tolerance (OVT) on all Data Ports up to 6 V without External Components

Applications

Cell Phone, PDA, Digital Camera, and Notebook

LCD Monitor, TV, and Set-Top Box

Description

The FSA3051 is a 6 Ω , bi-directional, low-power, two-port, high-speed, Single Pole / Double Throw (SPDT) analog switch. It features an extremely low on capacitance (C_{ON}) of 7.7 pF and wide bandwidth of 1.0 GHz.

The FSA3051 contains special circuitry on the switch VO pins for applications where the V_{CC} supply is powered-off (V_{CC} =0 V), which allows the device to withstand an over-voltage condition. This device is designed to minimize current consumption even when the control voltage applied to the select (S) pin is lower than the supply voltage (V_{CC}). This feature is especially valuable to ultra-portable applications, such as cell phones, allowing for direct interface with the general-purpose VOs of the baseband processor. Other applications include switching in portable cell phones, PDAs, digital cameras, printers, and notebook computers.

Ordering Information

Part Number	Top Mark	Operating Temperature Range	Package
FSA3051TMX	NT	-40 to +85°C	6-Lead, Dual, Ultra-ultrathin Molded Leadless Package (TMLP), 1.0 x 1.0 mm. Top left unit orientation in carrier tape.
FSA3051TMX-F147	NT	-40 to +85°C	6-Lead, Dual, Ultra-ultrathin Molded Leadless Package (TMLP), 1.0 x 1.0 mm. Bottom left unit orientation in carrier tape.

MicroPak™isa trademark of ON Semiconductor Corporation.

Analog Symbols

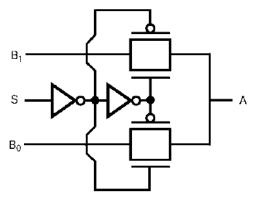


Figure 1. Logic Symbol

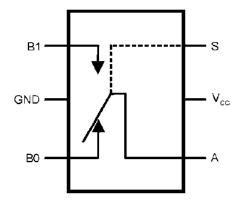


Figure 2. Analog Symbol

Pin Assignments

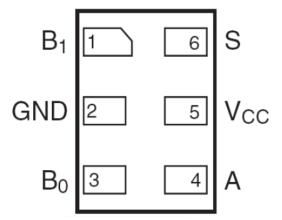


Figure 3. 6-Lead TMLP (Top-Through View)

Pin Definitions

UMLP Pin#	Name	Description
1	B ₁	Data Port
2	GND	Ground
3	B ₀	Data Port
4	Α	Data Port
5	Vcc	Supply Voltage
6	S	Sw itch Select

Truth Table

S	Function
LOW	B ₀ connected to A
HIGH	B ₁ connected to A

Notes:

- 1. LOW ≤V_{IL}.
- 2. HIGH ≥V_{IH}.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit	
Vcc	Supply Voltage		-0.5	6.0	V
V _{CNTRL}	DC Input Voltage ⁽³⁾		-0.5	V _{CC}	V
V _{SW}	DC Switch I/O Voltage ⁽³⁾		-0.50	6.00	V
l _{IK}	DC Input Diode Current	DC Input Diode Current			mA
ЮИТ	DC Output Current			50	mA
T _{STG}	Storage Temperature		-65	+150	°C
MSL	Moisture Sensitivity Level (JEDEC J-STD-020A)			1	Level
		All Pins	2		
ESD	Human Body Model, ANSI/ESDA/JEDEC JS-001-2012	I/O to GND	2		kV
EQD	33.23.2	Pow er to GND	2		۸V
	Charged Device Model, JEDEC: JESD22-C10	1	1		

Note:

3. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V _{CC}	Supply Voltage	1.6	5.5	V
V _{CNTRL}	Control Input Voltage (S) ⁽⁴⁾	0	V _{CC}	V
V _{SW}	Sw itch I/O Voltage	-0.5	5.5	V
T _A	Operating Temperature	-40	+85	°C

Note:

4. The control input must be held HIGH or LOW and it must not float.

DC Electrical Characteristics

All typical value are at T_A=25°C unless otherwise specified.

Symbol	Parameter	Condition	V _{cc} (V)	T _A =- 40°C to +85°C			Unit
Syllibol	Farameter	Condition	V _{CC} (V)	Min.	Тур.	Max.	Oilit
VIK	Clamp Diode Voltage	I _{IN} =-18 mA	3.0			-1.2	V
VIH	Input Voltage High		1.8 to 4.3	1.3			V
VIH	input voitage nigh		4.3 to 5.5	1.7			V
V _{IL}	Input Voltage Low		1.8 to 4.3			0.5	V
V IL	Input Voltage Low		4.3 to 5.5			0.7	V
lın	Control Input Leakage	V _{CNTRL} =0 to V _{CC}	1.8	-1		1	μΑ
IIN	Control liput Leakage	V CNTRL=O tO V CC	5.5	-1		1	μΑ
loz	Off State Leakage	V _{SW} =0 V to V _{CC}	1.8	-2		2	۸
102	On State Leakage	V _{SW} =0 V to 3.6 V	5.5	-2		2	μΑ
loff	Pow er-Off Leakage Current (All I/O Ports)	V _{SW} =0 V to 4.3 V, V _{CC} =0 V Figure 5	0	-2		2	μΑ
D	Sw itch On Resistance ⁽⁵⁾	V _{SW} =0.4 V, I _{ON} =-8 mA Figure 4	3.0		4	10	
R _{ON}	Switch On nesistance	V _{SW} =1.8 V, I _{ON} =-8 mA Figure 4	3.0		6	10	Ω
Б	Switch On Resistance ⁽⁵⁾	V _{SW} =0.4 V, I _{ON} =-8 mA Figure 4	1.8		6	10	
Ron	Switch On Resistance	V _{SW} =1.8 V, I _{ON} =-8 mA Figure 4	1.8		14	25	Ω
Λ D	On Resistance Match	V 0.4.V I 0.4	3.0		35		0
ΔR _{ON} Betw een Channels ^(5,6)		$V_{SW}=0.4 \text{ V}, I_{ON}=-8 \text{ mA}$	1.8		40		mΩ
lcc	Quiescent Supply Current	V _{CNTRL} =0 or V _{CC} , l _{OUT} =0	5.5			1	μΑ
		V _{CNTRL} =1.8 V	3.0			10	
Ісст	Increase in Icc Current per Control Voltage and Vcc	V _{CNTRL} =2.6 V	5.5			10	μΑ
	j j	V _{CNTRL} =1.8 V	5.5			15	

- Measured by the voltage drop between A and Bn pins at the indicated current through the switch. On resistance is determined by the lower of the voltage on the two (A or Bn ports). $\Delta R_{ON} = R_{ON} \text{ maximum } - R_{ON} \text{ minimum } \text{measured at identical } V_{CC}, \text{ temperature, } \text{ and voltage levels.}$
- Guaranteed by characterization.

AC Electrical Characteristics⁽⁸⁾

All typical value are for V_{CC} =3.3 V at T_{A} =25°C unless otherwise specified.

Symbol	Parameter	Condition	V _{cc} (V)	T _A =- 40°C to +85°C			Unit	
Syllibol	Parameter Condition		VCC (V)	Min.	Тур.	Max.	Oilit	
ton	Turn-On Time	R _L =50 Ω, C _L =5 pF, V _{SW} =0.8 V,	3.0 to 3.6		34		ns	
iON	S to Output	Figure 6, Figure 7	1.8		110		115	
toff	Turn-Off Time	RL=50 Ω , CL=5 pF, V _{SW} =0.8 V,	3.0 to 3.6		23		ns	
IOFF	S to Output	Figure 6, Figure 7	1.8		50		115	
top	t _{PD} Propagation Delay	C _L =5 pF, R _L =50 Ω , Figure 6, Figure 8	3.3		0.2		ns	
LPD			1.8		0.3		113	
t _{BBM}	Break-Before-Make	R_L =50 Ω , C_L =5 pF, V_{SW1} = V_{SW2} =0.8 V, Figure 9	3.0 to 3.6	15		50	ns	
rbbivi	Diean-Deiole-Mane		1.8			100	113	
O _{IRR}	Off Isolation	R _L =50 Ω, f=240 MHz, Figure 11	1.8		-20		dB	
OIRR	OII BOIALIOII	11 = 30 12, 1 = 2 +0 1VII 12, 1 1gui e 11	3.0 to 3.6		-23		uБ	
Xtalk	Crosstalk	R _L =50 Ω, f=240 MHz, Figure 12	1.8		-18		dB	
Atain	OI OSSIAIN	11_30 12, 1-240 Wilz, 11gule 12	3.0 to 3.6		-23		dB	
		RL=50 Ω , CL=0 pF, Vsw=0.4 V	1.8		810		MHz	
BW	-3 db Bandwidth	R _L =50 Ω , C _L =0 pF, Figure 10	3.0 to 3.6		1		GHz	
		R _L =50 Ω , C _L =5 pF, Figure 10	0.0 10 0.0		750		MHz	

Note:

Capacitance (9)

Symbol	Parameter	Condition	V _{cc} (V)	T _A =- 40°C to +85°C			11
				Min.	Тур.	Max.	Unit
C _{IN}	Control Pin Input Capacitance		0		1.5		
	f=1 MHz,	3.0		7.7			
Con	A Port On Capacitance	f=240 MHz, Figure 14	3.3		7.7		
CON	A FUIT OIT Capacitatice	f=1 MHz,	1.8		10.0		_
		f=240 MHz, Figure 14	1.8		5.0		pF
		f=1 MHz	3.0		3.3		
Coff	Bn Port Off Capacitance	f=240 MHz, Figure 13	3.3		3.3		
		f=1 MHz	1.8		5.0		
		f=240 MHz, Figure 13	1.8		4.0		

Note:

9. Not production tested.

^{8.} Guaranteed by characterization. Not production tested.

Test Diagrams

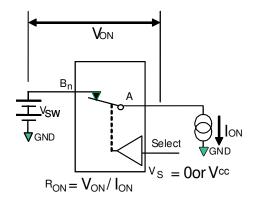
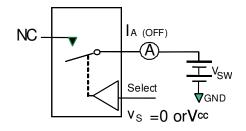
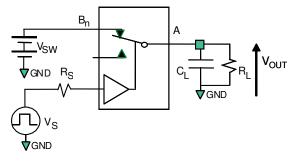


Figure 4. On Resistance



**Each switch port is tested separately

Figure 5. Off Leakage



 $\rm R_L$, $\rm R_S$, and $\rm C_L$ are functions of the application environment (see AC Tables for specific values) $\rm C_L$ includes test fixture and stray capacitance.

Figure 6. AC Test Circuit Load

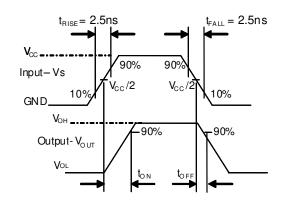


Figure 7. Turn-On / Turn-Off Waveforms

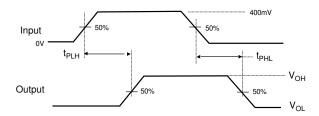


Figure 8. Propagation Delay (t_Rt_F – 500 ps)

Test Diagrams (Continued)

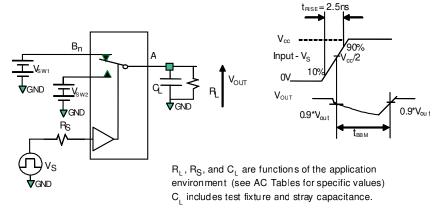


Figure 9. Break-Before-Make Interval Timing

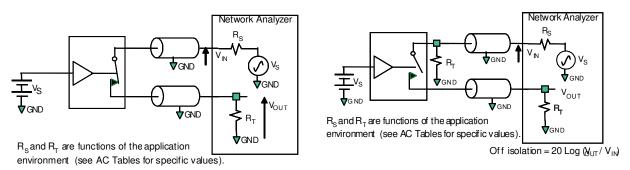


Figure 10. Bandwidth

Figure 11. Channel Off Isolation

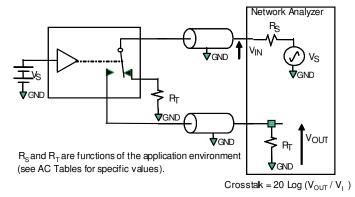
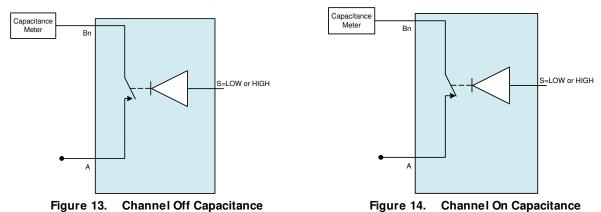


Figure 12. Channel-to-Channel Crosstalk



Carrier Tape Orientation

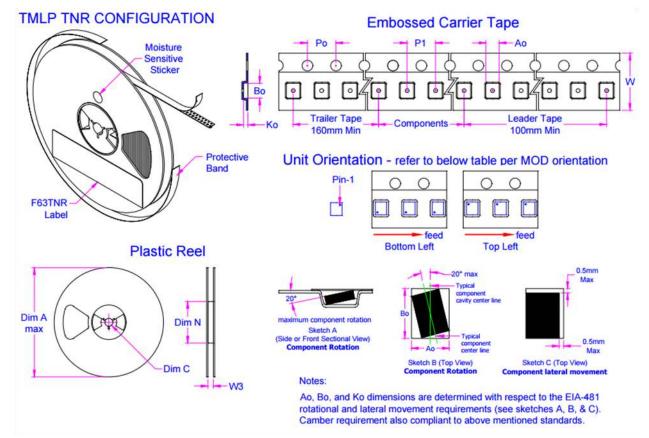
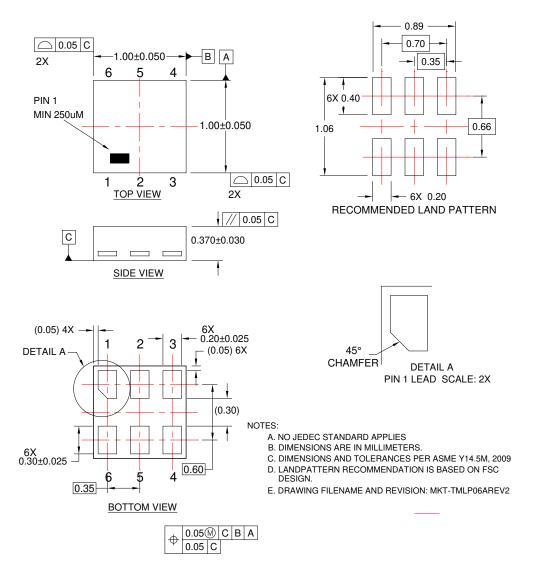


Figure 15. TMLP Carrier Tape Packing

Part Number	Unit Orientation
FSA3051TMX	Top Left
FSA3051TMX-F147	Bottom Left

Physical Dimensions



6-Lead, Dual, Ultra-ultrathin Molded Leadless Package (TMLP), 1.0 x 1.0 mm

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officer

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada

Email: orderlit@onsemi.com

N. Amer ic an Technical Support: 800-282-9855 Toll Free USA/Canada.

Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative